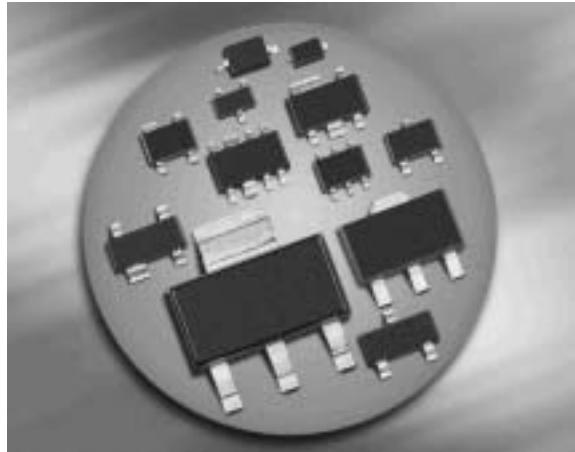
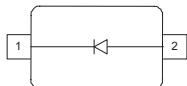


### Medium Power AF Schottky Diode

- Forward current: 750 mA  
Reverse voltage: 40 V
- For low-loss, fast-recovery, meter protection, bias isolation and clamping applications
- Pb-free (RoHS compliant) package<sup>1)</sup>
- Qualified according AEC Q101



### BAT165



**ESD (Electrostatic discharge) sensitive device, observe handling precaution!**

Type	Package	Configuration	Marking
BAT165	SOD323	single	C/White

**Maximum Ratings** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage <sup>2)</sup>	$V_R$	40	V
Forward current <sup>2)</sup>	$I_F$	750	mA
Average rectified forward current (50/60Hz, sinus)	$I_{FAV}$	500	mA
Non-repetitive peak surge forward current ( $t \leq 10\text{ms}$ )	$I_{FSM}$	2.5	A
Total power dissipation $T_S \leq 93^\circ\text{C}$	$P_{\text{tot}}$	600	mW
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{\text{stg}}$	-65 ... 150	

### Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>3)</sup>	$R_{\text{thJS}}$	$\leq 95$	K/W

<sup>1</sup>Pb-containing package may be available upon special request

<sup>2</sup>For  $T_A > 25^\circ\text{C}$  the derating of  $V_R$  and  $I_F$  has to be considered. Please refer to the attached curves.

<sup>3</sup>For calculation of  $R_{\text{thJA}}$  please refer to Application Note Thermal Resistance

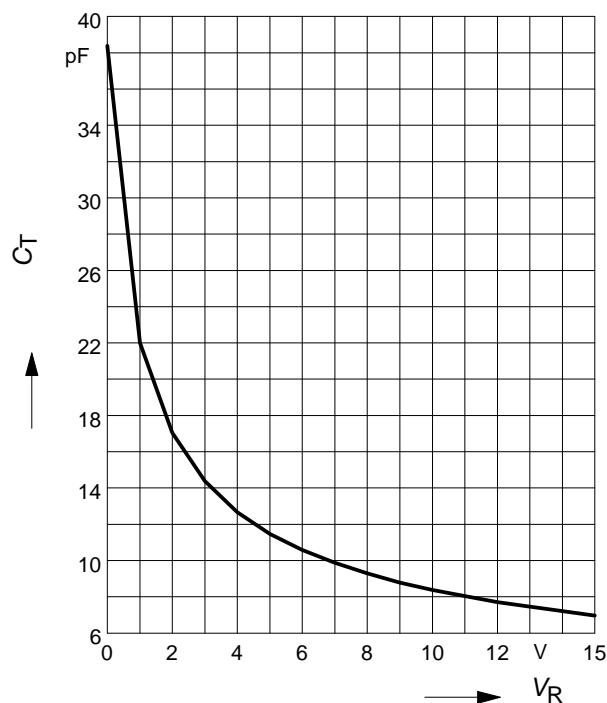
**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Reverse current <sup>1)</sup> $V_R = 30 \text{ V}$ $V_R = 40 \text{ V}$ $V_R = 40 \text{ V}, T_A = 65^\circ\text{C}$	$I_R$	-	-	12 50 900	$\mu\text{A}$
Forward voltage $I_F = 10 \text{ mA}$ $I_F = 100 \text{ mA}$ $I_F = 250 \text{ mA}$ $I_F = 750 \text{ mA}$	$V_F$	0.23 0.32 0.35 0.44	0.315 0.39 0.44 0.58	0.4 0.47 0.54 0.74	V
<b>AC Characteristics</b>					
Diode capacitance $V_R = 10 \text{ V}, f = 1 \text{ MHz}$	$C_T$	-	8.4	12	pF

<sup>1</sup>Pulsed test:  $t_p = 300 \mu\text{s}; D = 0.01$

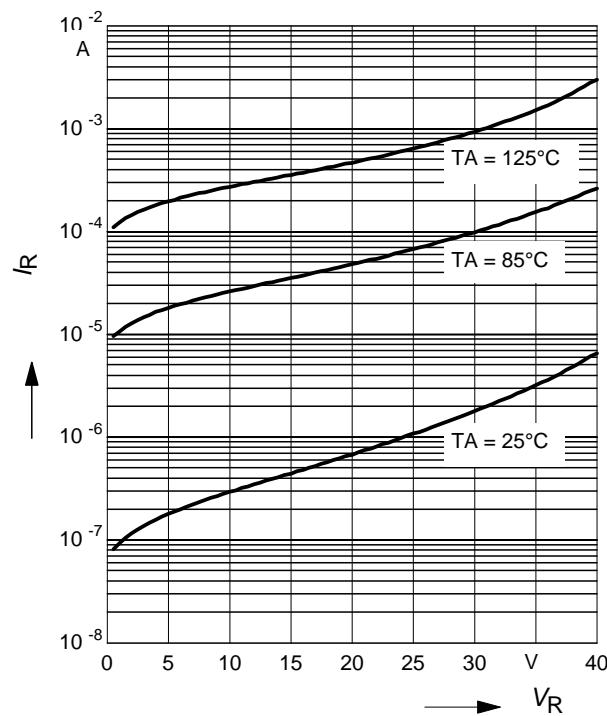
**Diode capacitance**  $C_T = f(V_R)$

$f = 1\text{MHz}$



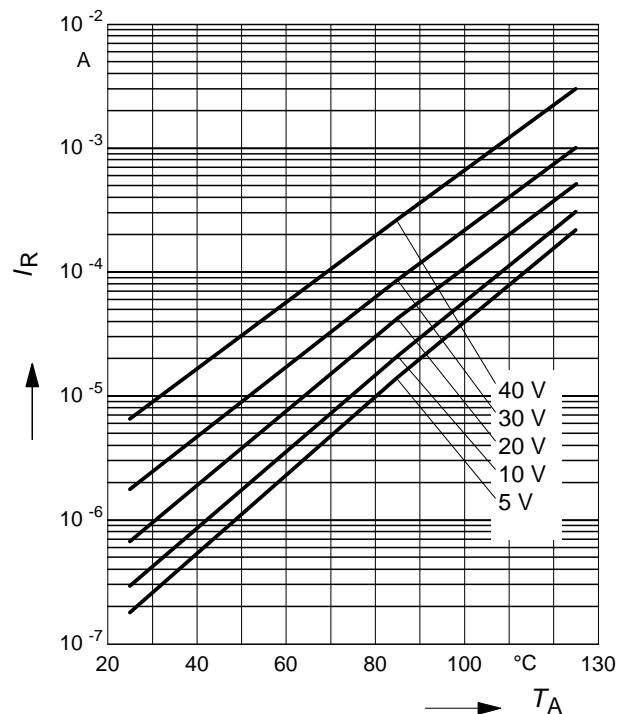
**Reverse current**  $I_R = f(V_R)$

$T_A$  = Parameter



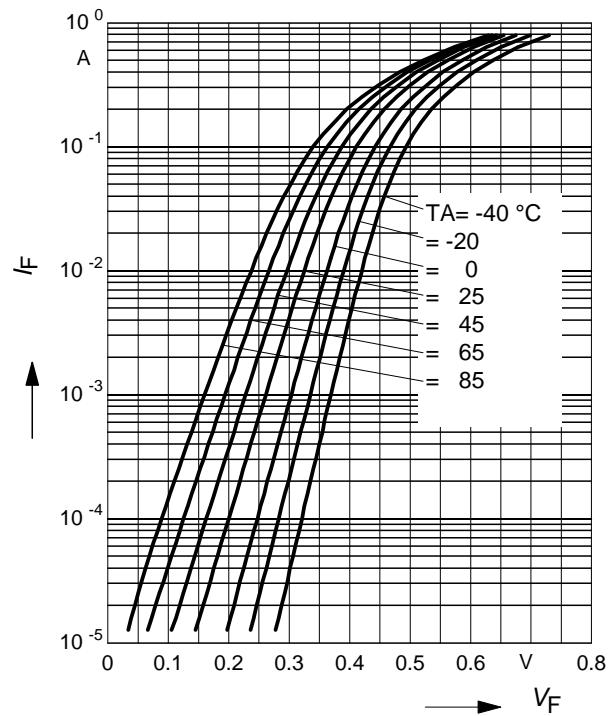
**Reverse current**  $I_R = f(T_A)$

$V_R$  = Parameter



**Forward current**  $I_F = f(V_F)$

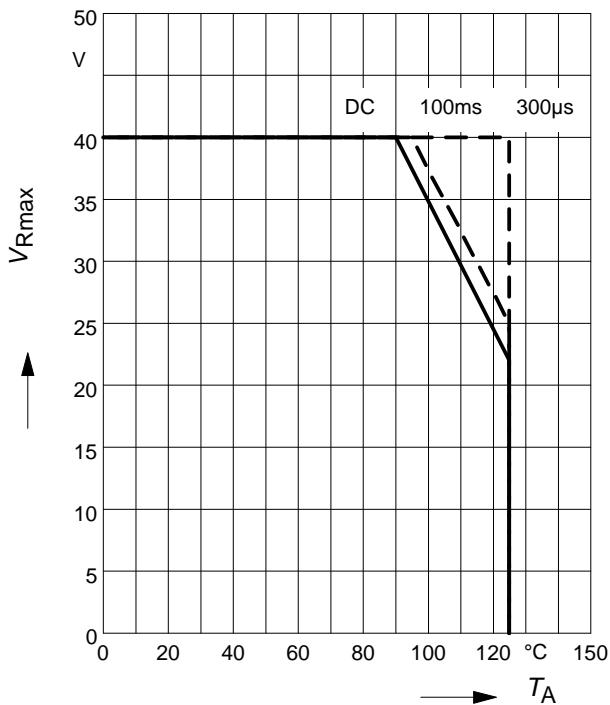
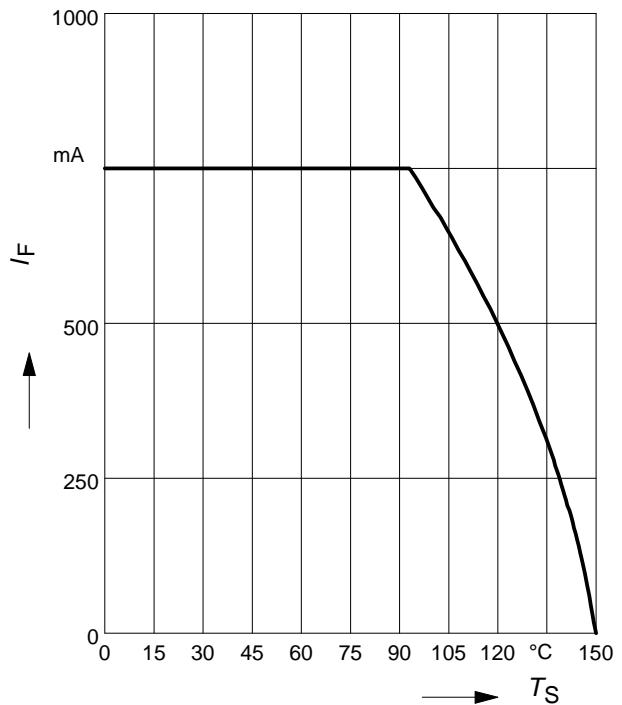
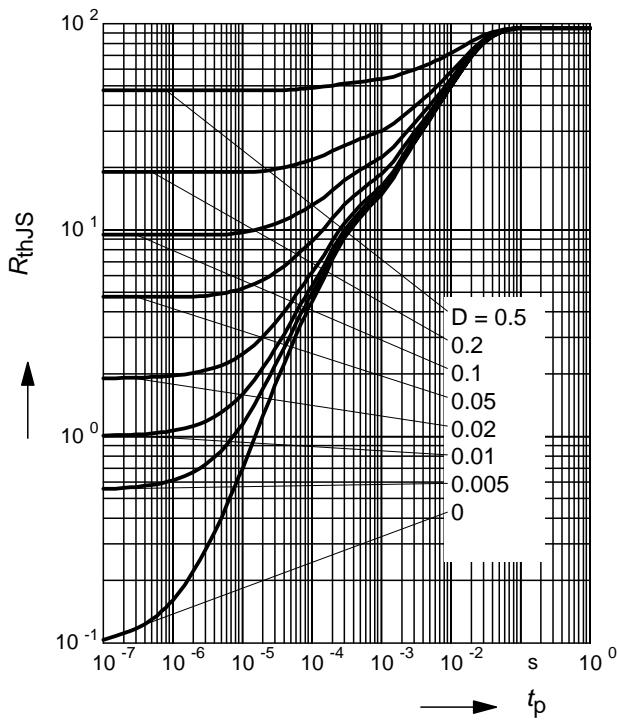
$T_A$  = Parameter



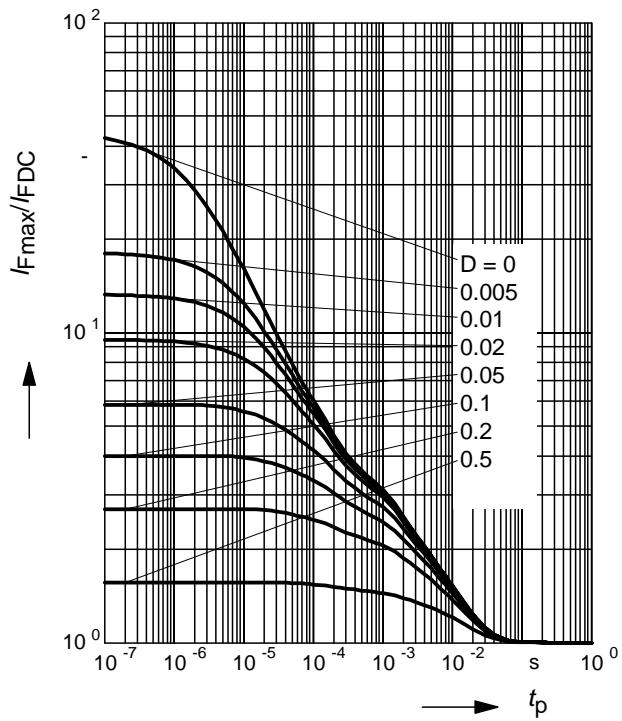
**Permissible Reverse voltage  $V_R = f(T_A)$** 

$t_p$  = Parameter, Duty cycle < 0.01

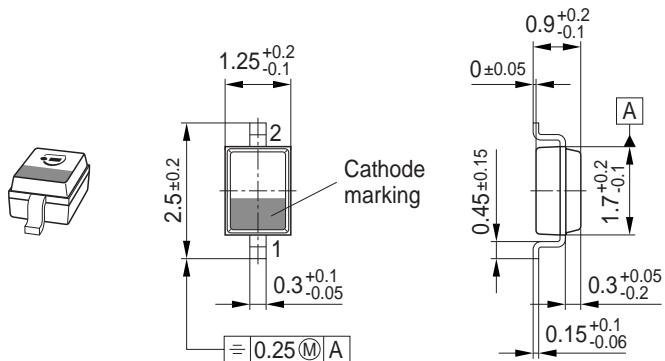
Device mounted on PCB with  $R_{th} = 160 \text{ k}\Omega$


**Forward current  $I_F = f(T_S)$** 

**Permissible Puls Load  $R_{thJS} = f(t_p)$** 

**Permissible Pulse Load**

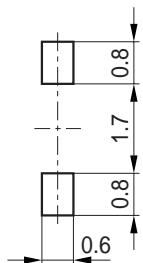
$$I_{Fmax}/I_{FDC} = f(t_p)$$



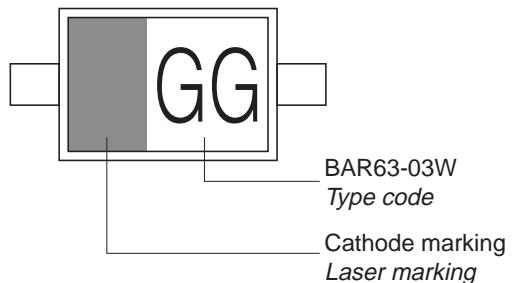
## Package Outline



## Foot Print

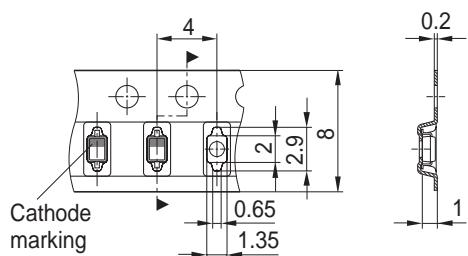


## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel  
 Reel ø330 mm = 10.000 Pieces/Reel



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